QUARLES & BRADY STREICH LANG LLP
Title: Method and Structure for Improving the Gate
Resistance of a Closed Cell Trench Power Mosfet
Inventors: Amato et al. Filing Date: 8/22/03
Attorney Docket No. 112518.00004

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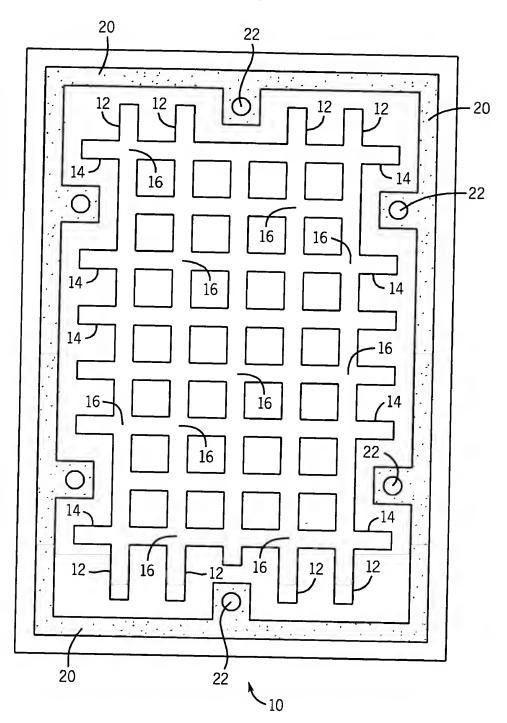


FIG. 1

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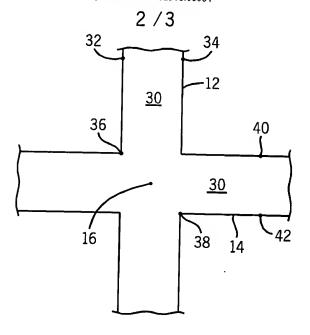


FIG. 2

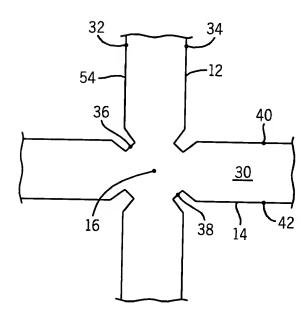
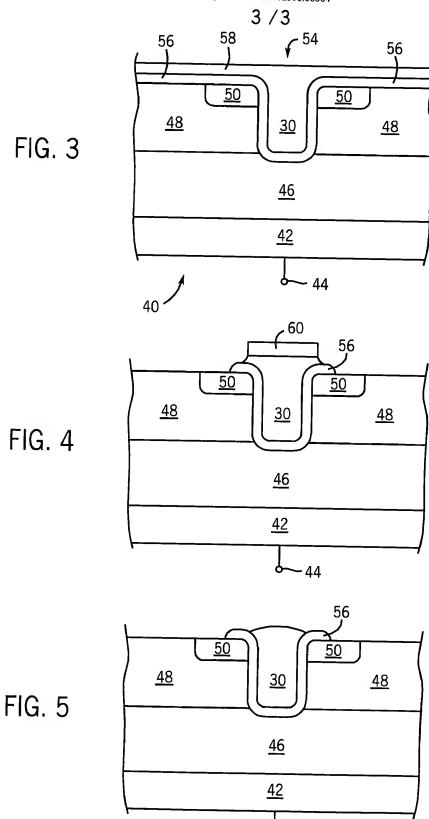


FIG. 6

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